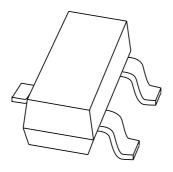
## DISCRETE SEMICONDUCTORS

# DATA SHEET



## BAP64-06 Silicon PIN diode

Product specification Supersedes data of 2000 Mar 22 2001 Feb 27





Silicon PIN diode BAP64-06

## **FEATURES**

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- · Low diode forward resistance
- Low series inductance
- For applications up to 3 GHz.

## **APPLICATIONS**

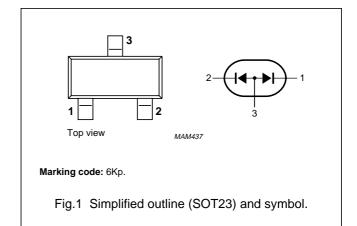
• RF attenuators and switches.

## **DESCRIPTION**

Two planar PIN diodes in common anode configuration in a SOT23 small SMD plastic package.

## **PINNING**

PIN	DESCRIPTION
1	cathode 1
2	cathode 2
3	common connection



## **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode			•		
V <sub>R</sub>	continuous reverse voltage		_	175	V
I <sub>F</sub>	continuous forward current		_	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>s</sub> = 90 °C	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

Silicon PIN diode BAP64-06

## **ELECTRICAL CHARACTERISTICS**

 $T_i = 25$  °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode			•	•	
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 50 mA	0.95	1.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 175 V	_	10	μΑ
		V <sub>R</sub> = 20 V	_	1	μΑ
C <sub>d</sub>	diode capacitance	f = 1 MHz			
		V <sub>R</sub> = 0	0.52	_	pF
		V <sub>R</sub> = 1 V	0.37	_	pF
		V <sub>R</sub> = 20 V	0.23	0.35	pF
r <sub>D</sub>	diode forward resistance	f = 100 MHz; note 1			
		$I_F = 0.5 \text{ mA}$	20	40	Ω
		I <sub>F</sub> = 1 mA	10	20	Ω
		I <sub>F</sub> = 10 mA	2	3.8	Ω
		I <sub>F</sub> = 100 mA	0.7	1.35	Ω
$\tau_{L}$	charge carrier life time	when switched from I <sub>F</sub> = 10 mA to	1.55	_	μs
		$I_R$ = 6 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 3 mA			
L <sub>S</sub>	series inductance		1.4	_	nH

## Note

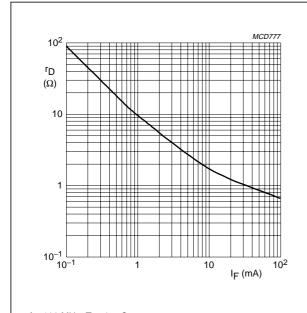
## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R <sub>th j-s</sub>	thermal resistance from junction to soldering point	220	K/W

<sup>1.</sup> Guaranteed on AQL basis: inspection level S4, AQL 1.0.

## Silicon PIN diode BAP64-06

## **GRAPHICAL DATA**



 $f = 100 \text{ MHz}; T_j = 25 \,^{\circ}\text{C}.$ 

Fig.2 Forward resistance as a function of forward current; typical values.

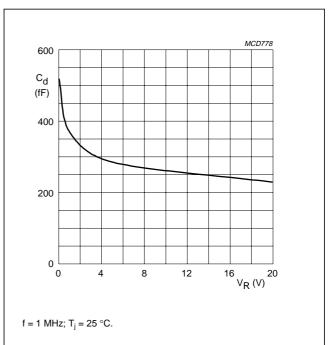
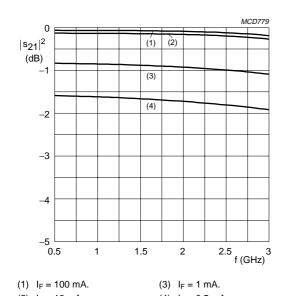


Fig.3 Diode capacitance as a function of reverse voltage; typical values.

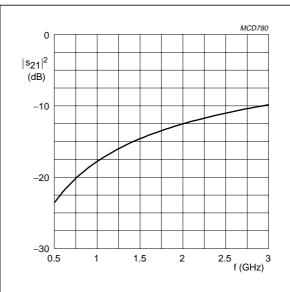


- (2)  $I_F = 10 \text{ mA}.$
- (4)  $I_F = 0.5 \text{ mA}.$

4

Diode inserted in series with a 50  $\Omega$  stripline circuit and biased via the analyzer Tee network; T  $_{amb}$  = 25  $^{\circ}C$  .

Fig.4 Insertion loss  $(|s_{21}|^2)$  of the diode as a function of frequency; typical values.



Diode zero biased and inserted in series with a 50  $\Omega$  stripline circuit;  $T_{amb}$  = 25  $^{\circ}C.$ 

Fig.5 Isolation ( $|s_{21}|^2$ ) of the diode as a function of frequency; typical values.

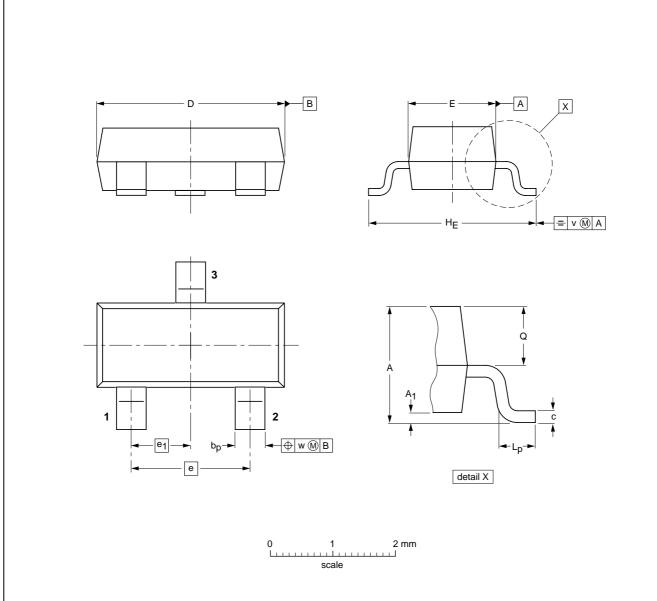
2001 Feb 27

Silicon PIN diode BAP64-06

## **PACKAGE OUTLINE**

## Plastic surface mounted package; 3 leads

SOT23



## **DIMENSIONS (mm are the original dimensions)**

UNIT	Α	A <sub>1</sub> max.	bp	С	D	E	е	e <sub>1</sub>	HE	L <sub>p</sub>	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC JEDEC		EIAJ		PROJECTION	ISSUE DATE
SOT23		TO-236AB				<del>-97-02-28-</del> 99-09-13

Silicon PIN diode BAP64-06

#### **DATA SHEET STATUS**

DATA SHEET STATUS	PRODUCT STATUS	DEFINITIONS (1)
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

### Note

1. Please consult the most recently issued data sheet before initiating or completing a design.

#### **DEFINITIONS**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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